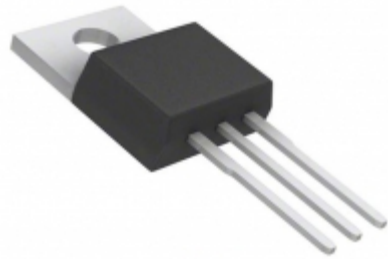


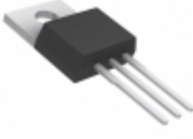
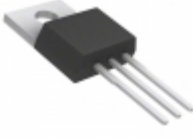






	<h2 style="color: red;">FQP4N90C</h2>
	Hersteller-Teilenummer: FQP4N90C
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 900V 4A TO-220
	Datenblätter: <ul style="list-style-type: none">  1.FQP4N90C.pdf  2.FQP4N90C.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 19980 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP4N90C
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 900V 4A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	19980 pcs Stock
detaillierte Beschreibung	N-Channel 900V 4A (Tc) 140W (Tc) Through Hole TO-
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	140W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	900V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4A (Tc)
Rds On (Max) @ Id, Vgs	4.2 Ohm @ 2A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	22nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	960pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































FQP4N90C ist neu im Original, Suche FQP4N90C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP4N90C AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP4N90C: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP4P25 Fairchild/ON Semiconductor MOSFET P-CH 250V 4A TO-220</p>	 <p>FQP4N90 Fairchild/ON Semiconductor MOSFET N-CH 900V 4.2A TO-220</p>	 <p>FQP4N90 AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 4.2A TO-220</p>	 <p>FQP4N65C VB FQP4N65C VB</p>
 <p>FQP4P40 AMI Semiconductor / ON Semiconductor MOSFET P-CH 400V 3.5A TO-220</p>	 <p>FQP4N80 Fairchild/ON Semiconductor MOSFET N-CH 800V 3.9A TO-220</p>	 <p>FQP4P40 Fairchild/ON Semiconductor MOSFET P-CH 400V 3.5A TO-220</p>	 <p>FQP4P25 AMI Semiconductor / ON Semiconductor MOSFET P-CH 250V 4A TO-220</p>

heiße Teile

Mehr

 FQP44N08	 FQP44N10	 FQP44N10	 FQP44N10F	 FQP44N10F
 FQP45N03L	 FQP45N03LM	 FQP45N15V2	 FQP45N15V2	 FQP45N20A
 FQP46N15	 FQP46N15	 FQP47N06	 FQP47P06	 FQP47P06
 FQP47P06L	 FQP47P06_	 FQP47P06_NW82049	 FQP47P06_NW82049	 FQP47P06_SW82049
 FQP47P06_SW82049	 FQP4N20L	 FQP4N20L	 FQP4N60C	 FQP4N65C
 FQP4N90C	 FQP50N03	 FQP50N03C	 FQP50N06	 FQP50N06
 FQP50N06L	 FQP50N06L	 FQP50N08	 FQP55N06	 FQP55N06
 FQP55N10	 FQP55N10	 FQP58N08	 FQP58N08	 FQP5N20L
 FQP5N20L	 FQP5N50C	 FQP5N50C	 FQP5N60C	 FQP5N60C
 FQP630TSTU	 FQP630TSTU	 FQP65N06	 FQP65N06	 FQP6N40C

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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